

# Alpha & Omega Semiconductor Product Reliability Report



**Plastic Encapsulated Device** 

**ALPHA & OMEGA Semiconductor, Inc** 

www.aosmd.com



This AOS product reliability report summarizes the qualification results for AOZ29303QI in QFN9x6\_48L package. Accelerated environmental tests are performed on a specific sample size and samples are electrically tested before and after each time point. Review of final electrical test results confirm that AOZ29303QI pass the AOS quality and reliability requirements. The released products will be categorized by its process family and routinely monitored for continuous improvement of product quality.

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Test Item	Test Condition	Time Point	Total Sample Size	Number of Failures	Reference Standard
HTOL	Temp = 125°C, VIN=Vccmax	168 / 500/1000 hours	240 pcs	0	JESD22-A108
Preconditioning (Note A)	T <sub>A</sub> = 30°C, RH = 60% + 3 cycle reflow @ 260°C (MSL 3)	168 hours	924 pcs	0	JESD22-A113
HAST	T <sub>A</sub> = 130°C, RH = 85%, P = 33.3psia, V <sub>IN</sub> = Vccmax	96 hours	240 pcs	0	JESD22-A110
Pre-con + PCT (autoclave)	T <sub>A</sub> = 121°C, RH = 100%, P = 29.7psia	96 hours	240 pcs	0	JESD22-A102
Pre-con + Temp Cycles	T <sub>A</sub> = -40°C to 125°C, air to air	250 / 500 / 1000 cycles	240 pcs	0	JESD22-A104
Pre-con + Temp Cycles	T <sub>A</sub> = -55°C to 150°C, air to air	250 / 500 / 1000 cycles	240 pcs	0	JESD22-A104
HTSL	Temp = 150°C	168 / 500 / 1000 hours	240 pcs	0	JESD22-A103
Pre-con + THB	85C, 85%RH, 7.12psia, VIN=Vcc max	1000 hours	240 pcs	0	JESD22-A101

Note: The reliability data presents total of available generic data up to the published date.

Note A: MSL (Moisture Sensitivity Level) 3 based on J-STD-020

#### II. Reliability Evaluation

#### FIT rate (per billion): 12.36 MTTF = 80.9 million years

The presentation of FIT rate for the individual product reliability is restricted by the actual burn-in sample size. Failure Rate Determination is based on JEDEC Standard JESD 85. FIT means one failure per billion hours.

Failure Rate =  $Chi^2 \times 10^9 / [2 (N) (H) (Af)] = 12.36$ MTTF =  $10^9 / FIT = 80.9$  million years

 $Chi^2$  = Chi Squared Distribution, determined by the number of failures and confidence interval N = Total Number of units from burn-in tests

H = Duration of burn-in testing

**Af** = Acceleration Factor from Test to Use Conditions (Ea = 0.7eV and  $T_{use} = 55^{\circ}$ C) Acceleration Factor [**Af**] = **Exp** [Ea / k (1/T<sub>J</sub> u - 1/T<sub>J</sub> s)]

Acceleration Factor ratio list:

	55 deg C	70 deg C	85 deg C	100 deg C	115 deg C	125 deg C
Af	77	26	9.8	3.9	1.7	1

 $T_J s$  = Stressed junction temperature in degree (Kelvin), K = C + 273.16

 $T_J u$  =The use junction temperature in degree (Kelvin), K = C + 273.16

 $\mathbf{k}$  = Boltzmann's constant, 8.617164 X 10<sup>-5</sup>eV / K



## ELECTROSTATIC DISCHARGE, LATCH UP TEST REPORT

Part Number: AOZ29303QI Package: QFN9x6\_48L

ESD, LATCH UP RESULTS							
Test	Specification	Conditions	Temperature	Sample Size	Results <sup>(1)</sup>		
Electrostatic Discharge	JESD-A114	±1.5kV (HBM)	25C	3	PASS		
Electrostatic Discharge	JESD-C101	±1kV (CDM)	25C	3	PASS		
Latch Up	JESD78	±100mA, 1.5x OV	25C	6	PASS		
Latch Up	JESD78	±100mA, 1.5x OV	125C	6	PASS		

(1) ATE results are used to determine PASS/FAIL. Parametric shift <10%.

### **Pin Configuration**

